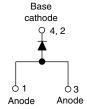


# High Performance Schottky Rectifier, 5.5 A





7 mJ

**D-PAK (TO-252AA)** 

 $\mathsf{E}_{\mathsf{AS}}$ 

PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
$I_{F(AV)}$	5.5 A						
$V_{R}$	60 V						
V <sub>F</sub> at I <sub>F</sub>	See Electrical table						
$I_{RM}$	35 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Single die						

#### **FEATURES**

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

The VS-50WQ06FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	5.5	А						
$V_{RRM}$		60	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	320	А						
V <sub>F</sub>	5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.54	V						
T <sub>J</sub>	Range	-40 to +150	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-50WQ06FNPbF	UNITS				
Maximum DC reverse voltage	$V_{R}$	60	V				
Maximum working peak reverse voltage	$V_{RWM}$	00	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 132 °C	5.5					
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated	320	Α			
See fig. 7		10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	105				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 1.2  \text{A},  L = 10  \text{n}$	7	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximo	0.8	Α				



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		5 A	T <sub>.1</sub> = 25 °C	0.57	V			
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	11 = 23 0	0.74				
See fig. 1	VFM (*)	5 A	T <sub>.1</sub> = 125 °C	0.54				
		10 A	1j = 125 C	0.68				
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	3	- mA			
See fig. 2		T <sub>J</sub> = 125 °C	VR = nateu VR	35				
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum	T. T		V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		25.5	mΩ			
Typical junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	360	pF				
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 r	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS									
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	3.0	°C/W					
Approximate weight			0.3	g					
Approximate weight			0.01	oz.					
Marking device		Case style D-PAK (similar to TO-252AA)	50WC	06FN					

### Note

(1) 
$$\frac{dP_{tot}}{dT_1} < \frac{1}{R_{tb,1,\Delta}}$$
 thermal runaway condition for a diode on its own heatsink

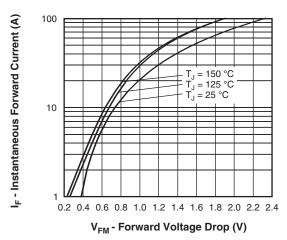


Fig. 1 - Maximum Forward Voltage Drop Characteristics

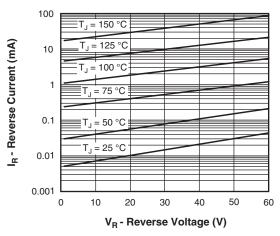


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

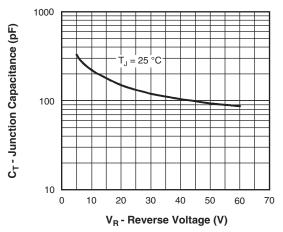


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

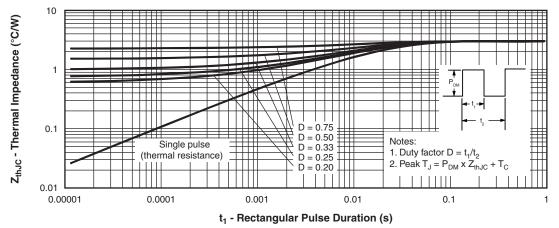


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





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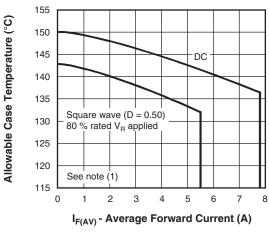


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

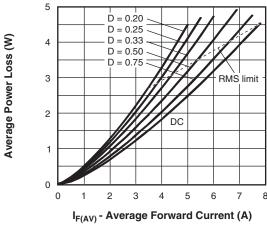


Fig. 6 - Forward Power Loss Characteristics

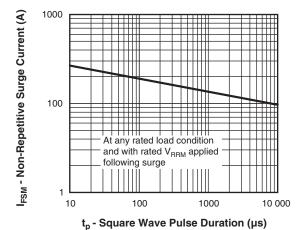


Fig. 7 - Maximum Non-Repetitive Surge Current

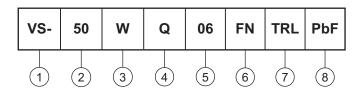
#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>



#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (5.5 A)

3 - Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (06 = 60 V)

- FN = TO-252AA (D-PAK)

None = tube (50 pieces)

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

PbF = lead (Pb)-free

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95016</u>							
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						



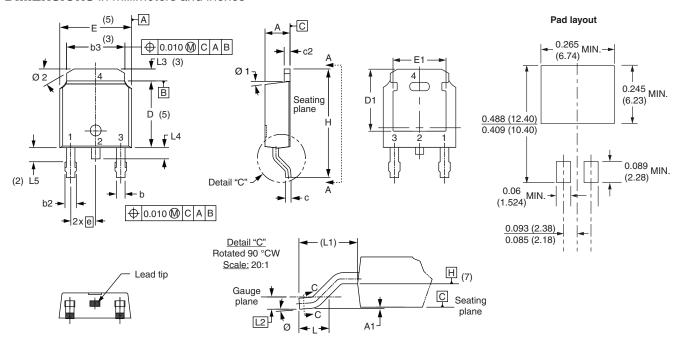
**NOTES** 

3

2

# **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	NOTES	HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDOL	MIN.	MAX.	MIN.	MAX.		
Α	2.18	2.39	0.086	0.094			e 2.29 BSC		0.090 BSC				
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410		
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070		
b2	0.76	1.14	0.030	0.045			L1	2.74 BSC		0.108 REF.			
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC		
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050		
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040		
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060		
D1	5.21	-	0.205	1	3		Ø	0°	10°	0°	10°		
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°		
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°		

### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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